OSRAM SFH 4180BS **Datasheet**

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OSLON® P1616

SFH 4180BS









Applications

- Access Control & Security
- Authentication
- Eye, face and hand tracking

- Factory Automation
- Home & Building Automation
- Medical Lighting

Features

- Package: clear silicone
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM)
- IR lightsource with high efficiency
- Double stack emitter



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Orde	2rina	Inforr	nation

Туре	Total radiant flux $^{1)2)}$ $I_F = 1 \text{ A}; t_p = 10 \text{ ms}$ Φ_e	Total radiant flux ¹⁾ typ. $I_F = 1 \text{ A}; t_p = 10 \text{ ms}$ Φ_e	Ordering Code
SFH 4180BS-FA2FB2-11	1250 1800 mW	1,485 mW	Q65113A4988
SFH 4180BS-FA2FB2-1113	1250 1800 mW	1,485 mW	Q65113A8781
SFH 4180BS-FA2FB2-13	1250 1800 mW	1,485 mW	Q65113A8780



Maximum Ratings

T_A = 25 °C

Parameter	Symbol	Symbol	
Operating temperature	T_{op}	min.	-40 °C
	οp	max.	105 °C
Storage temperature	T _{stg}	min.	-40 °C
	3.g	max.	105 °C
Junction temperature	T_{j}	max.	145 °C
Forward current	I _F	min.	10 mA
	·	max.	1000 mA
Forward current pulsed	 F pulse	max.	2 A
$t_{p} \le 700 \mu\text{s}; D \le 0.005$	i puise		
Reverse voltage 3)	V_R	max.	5 V
ESD withstand voltage	V_{ESD}	max.	2 kV
acc. to ANSI/ESDA/JEDEC JS-001 (HBM)	200		

Note: The maximum forward current dimming range shall not be larger than 10.



Characteristics

 $I_{_{\rm F}}$ = 1000 mA; $t_{_{
m D}}$ = 10 ms; $T_{_{
m A}}$ = 25 °C

Parameter	Symbol		Values
Centroid wavelength 4)	$\lambda_{ ext{centroid}}$	min. max.	912 nm 950 nm
Spectral bandwidth at 50% I _{rel,max} (FWHM)	Δλ	typ.	37 nm
Half angle	φ	typ.	65 °
Dimensions of chip area	LxW	typ.	0.73 x 0.73 mm x mm
Rise time (10% / 90%) $I_F = 1 \text{ A}; R_L = 5 \Omega$	t _r	typ.	12 ns
Fall time (10% / 90%) $I_F = 1 \text{ A}; R_L = 5 \Omega$	t _f	typ.	11.5 ns
Forward voltage 5)	V_{F}	typ. max.	2.8 V 3.2 V
Forward voltage $^{5)}$ I _F = 2 A; t _D = 100 µs	V_{F}	typ. max.	3.0 V 3.7 V
Reverse current ³⁾ V _R = 5 V	I _R	typ. max.	0.01 μA 10 μA
Radiant intensity $^{6)}$ I _F = 1A, t _p = 100 µs	l _e	typ.	325 mW/sr
Thermal resistance junction solder point electrical $^{7)}$ with efficiency η_e = 53 %	R _{thJS elec.}	typ. max.	6.2 K / W 7.4 K / W



Brightness Groups

Group Total radiant flux $^{1)2)}$ $I_F = 1 \text{ A}; t_p = 10 \text{ ms}$ min.		Total radiant flux $^{1)2)}$ $I_F = 1 \text{ A}$; $t_p = 10 \text{ ms}$ max.	
	$\Phi_{ m e}$	Φ_{e}	
FA2	1250 mW	1400 mW	
FB1	1400 mW	1600 mW	
FB2	1600 mW	1800 mW	

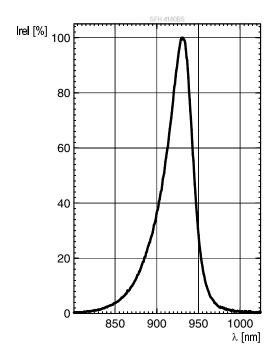
Centroid Wavelength

Group Centroid wavelength 4)		Centroid wavelength 4)	
	$I_{F} = 1 \text{ A; } t_{p} = 10 \text{ ms}$	$I_F = 1 A; t_p = 10 ms$	
	min.	max.	
	$\lambda_{centroid}$	$\lambda_{ ext{centroid}}$	
11	912 nm	925 nm	
12	925 nm	930 nm	
13	930 nm	950 nm	



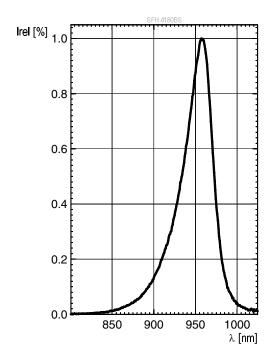
Relative Spectral Emission 8), 9)

Centroid wavelength 920 nm



Relative Spectral Emission 8), 9)

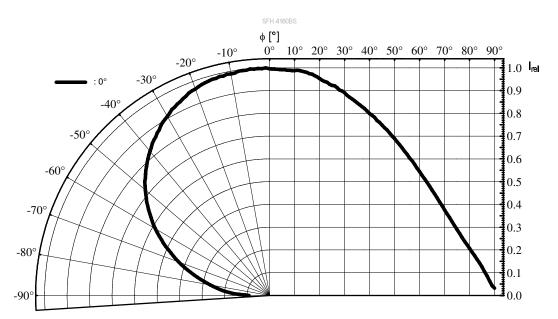
Centroid wavelength 940 nm





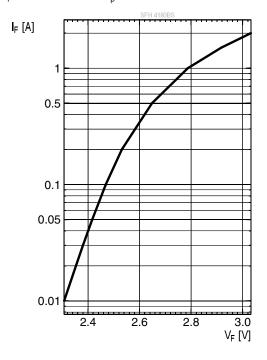
Radiation Characteristics 8), 9)

 $I_{e,rel} = f(\phi)$



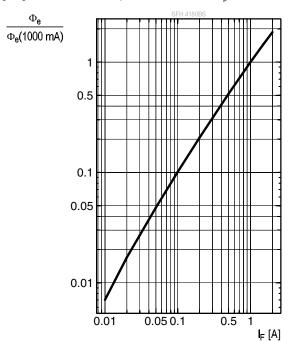
Forward current 8), 9)

 $I_{_F}$ = f ($V_{_F}$); single pulse; $t_{_p}$ = 100 μs



Relative Total Radiant Flux 8), 9)

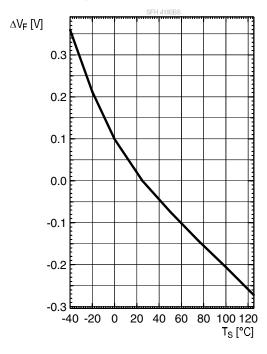
 $\Phi_{\rm e}/\Phi_{\rm e}(1000{\rm mA})$ = f (I_F); single pulse; t_p = 100 $\mu {\rm s}$





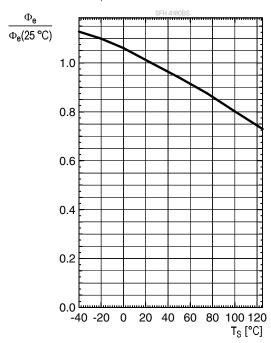
Forward Voltage 8)

$$V_F = f(T_S); I_F = 1A; t_p = 100 \mu s$$



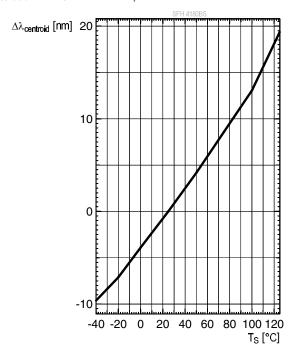
Relative Total Radiant Flux 8)

$$\Phi_{rel} = f(T_s); I_F = 1A; t_p = 100 \mu s$$



Centroid Wavelength 8)

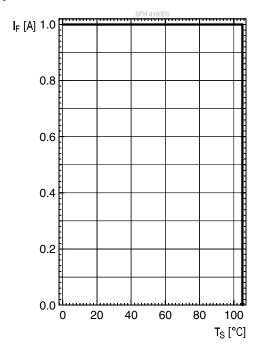
$$\lambda_{centroid} = f(T_S); I_F = 1A; t_p = 100 \mu s$$





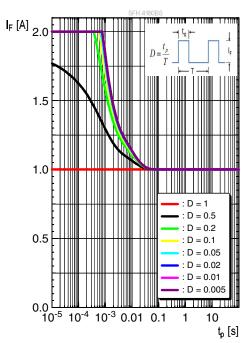
Max. Permissible Forward Current

 $I_F = f(T_S)$



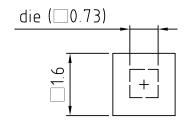
Permissible Pulse Handling Capability

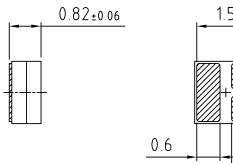
 $I_F = f(t_p)$; duty cycle D = parameter; $T_S = 85$ °C

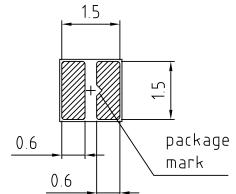




Dimensional Drawing 10)







general tolerance ± 0.05 lead finish Au

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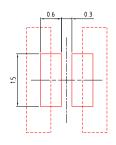
Further Information:

Approximate Weight: 6.0 mg

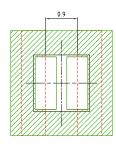
Package marking: Cathode



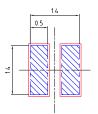
Recommended Solder Pad 10)











solder stencil recommended stencil thickness 120µm

Component Location on Pad



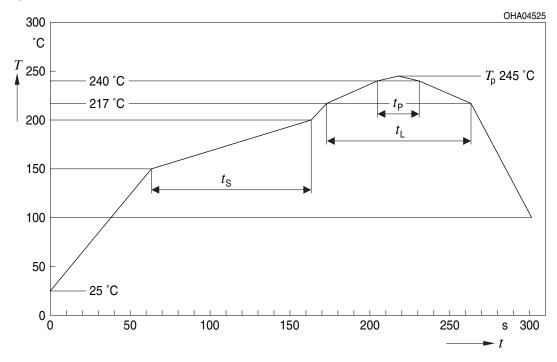


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Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



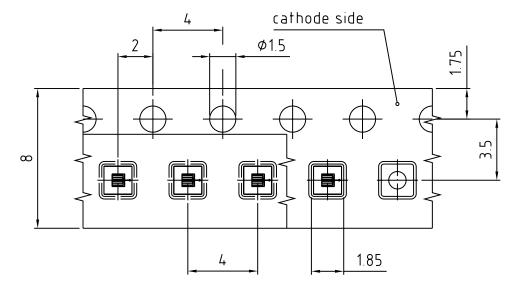
Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*)	'		2	3	K/s
25 °C to 150 °C					
Time t _s	t _s	60	100	120	S
T_{Smin} to T_{Smax}					
Ramp-up rate to peak*)			2	3	K/s
T_{Smax} to T_{P}					
Liquidus temperature	T_{L}		217		°C
Time above liquidus temperature	$t_{\scriptscriptstyle \perp}$		80	100	S
Peak temperature	T _P		245	260	°C
Time within 5 °C of the specified peak temperature T _p - 5 K	t _P	10	20	30	S
Ramp-down rate* T _P to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

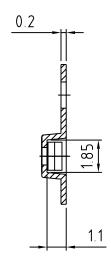
All temperatures refer to the center of the package, measured on the top of the component

 $^{^{\}star}$ slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



Taping 10)

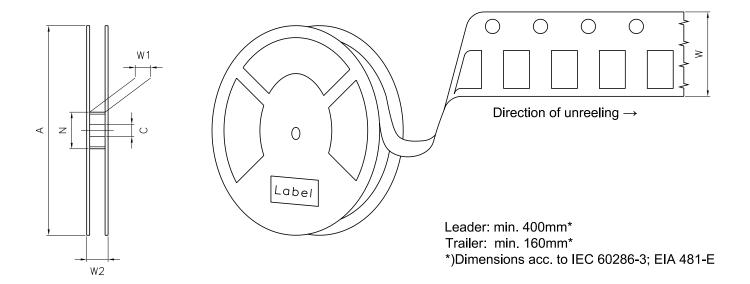




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Tape and Reel 11)



Reel Dimensions

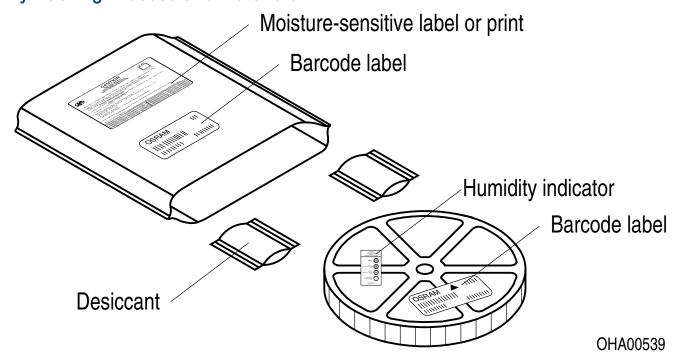
Α	W	N_{\min}	W_1	$W_{2\text{max}}$	Pieces per PU
180 mm	8 + 0.3 / - 0.1 mr	n 60 mm	8.4 + 2 mm	14.4 mm	4000



Barcode-Product-Label (BPL)



Dry Packing Process and Materials



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into **exempt risk group - Exempt**.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

Handling:

Solvents, water, liquids, non-conductive plastics and glues are not allowed near the device, because solvents and other liquids could emerge and damage the product.

For further application related information please visit https://ams-osram.com/support/application-notes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



Glossary

- 1) Total radiant flux: Measured with integrating sphere.
- 2) **Brightness:** The brightness values are measured with a tolerance of ±11%.
- 3) Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- 4) Wavelength: The wavelengths are measured with a tolerance of ±1 nm.
- 5) Forward Voltage: The forward voltages are measured with a tolerance of ±0.1 V.
- 6) **Radiant intensity:** Measured at a solid angle of Ω = 0.01 sr
- 7) Thermal resistance: junction - soldering point, of the device only, mounted on an ideal heatsink (e.g. metal block)
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 9) **Testing temperature:** TA = 25°C (unless otherwise specified)
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- Tape and Reel: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

SFH 4180BS DATASHEET



Revision History				
Version	Date	Change		
1.0	2024-08-13	Electro - Optical Characteristics (Diagrams) Characteristics		



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

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